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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No.: unknown Confirmation No.:  
Applicant: BURNS, *et al.*  
Filed: unknown  
TC/A.U.: unknown  
Examiner: unknown  
Docket No.: DC5180 PCT1  
Customer No.: 00137  
Date: 17 May 2006  
For: Method of Removing Impurities From Metallurgical Grade Silicon to  
Produce Solar Grade Silicon

**PRELIMINARY AMENDMENT TO U.S. FILING UNDER 35 U.S.C. §371 OF PCT  
APPLICATION NO. PCT/US2004/027846 FILED: 27 AUGUST 2004**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**INTRODUCTORY COMMENTS**

Sir:

The applicants respectfully request entry of the following preliminary amendment. The applicants request calculation of any fee amounts after entry of the amendment.